





60V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > -60V
- I_C = -6A Continuous Collector Current
- Low Saturation Voltage V_{CE(sat)} < -95mV max @ -1A
- $R_{CE(sat)} = 40m\Omega$ for a low Equivalent On-Resistance
- h_{FE} Specified up to -10A for a High Gain Hold-Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

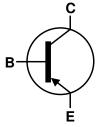
Applications

- Motor Driving
- DC-DC Modules
- Backlight Inverters
- Actuator, Relay, and Solenoid Drivers

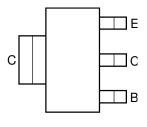
SOT223



Top View



Device Symbol



Top View Pin-Out

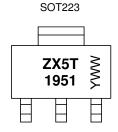
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZX5T1951GTA	ZX5T1951	7	12	1,000

Notes:

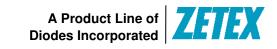
- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-Free, "Green" and Lead-Free.
- 3. Halogen- and Antimony-Free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



ZX5T1951 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)





Absolute Maximum Ratings (@ $T_A = +25$ $^{\circ}$ C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-90	V
Collector-Emitter Voltage	V _{CES}	-90	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current (Note 5)	Ic	-6	Α
Peak Pulse Current	I _{CM}	-15	Α
Base Current	I _B	-1	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	0	3.0 24	W
Linear Derating Factor	(Note 6)	- P _D	1.6 12.8	mW /℃
Thermal Decistance Junction to Ambient	(Note 5)	$R_{\theta JA}$	42	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	78	°C/W
Thermal Resistance Junction to Lead (Note 7)		$R_{\theta JL}$	12.3	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	℃	

ESD Ratings (Note 8)

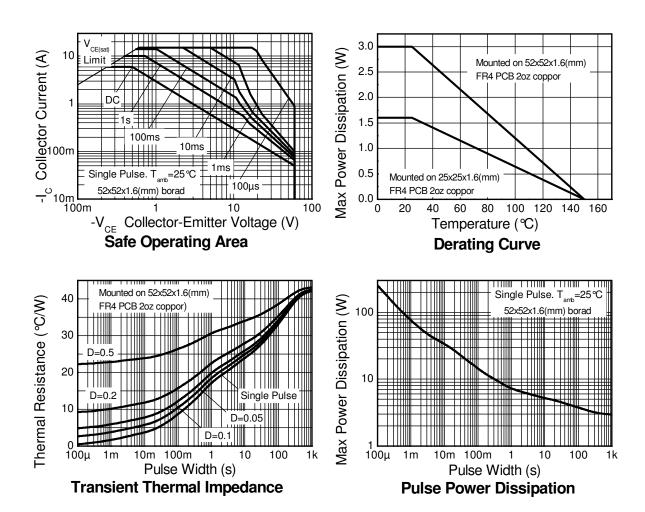
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

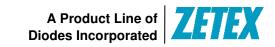
- 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics







Electrical Characteristics (@T_A = +25 °C, unless otherwise specified.)

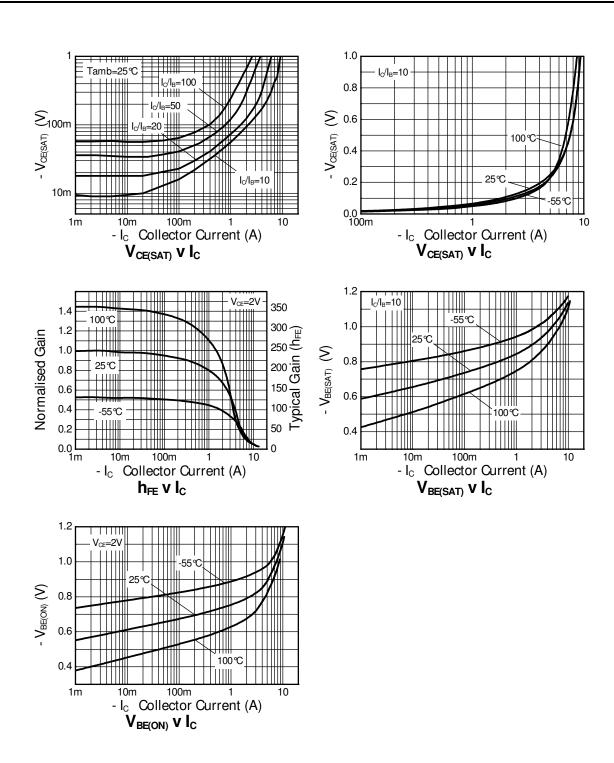
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-90	-120	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage	BV _{CES}	-90	-120	-	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-60	-80	-	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8	-	V	$I_E = -100\mu A$
Collector-Base Cut-Off Current	I _{CBO}	-	<1	-50	nA	V _{CB} = -72V
Collector-Emitter Cut-Off Current	I _{CES}	-	<1	-50	nA	V _{CB} = -72V
Emitter Cutoff Current	I _{EBO}	-	<1	-10	nA	$V_{EB} = -6V$
		100	240	-		$I_{C} = -10 \text{mA}, V_{CE} = -2 \text{V}$
Static Forward Current Transfer Patic (Note 0)	h	100	180	300		$I_{C} = -2A, V_{CE} = -2V$
Static Forward Current Transfer Ratio (Note 9)	h _{FE}	40	70	-	-	$I_{C} = -5A$, $V_{CE} = -2V$
		5	14	-		$I_C = -10A$, $V_{CE} = -2V$
		-	-16	-30	- mV	$I_C = -100 \text{mA}, I_B = -10 \text{mA}$
Collector-Emitter Saturation Voltage (Note 9)	V	-	-55	-95		$I_C = -1A$, $I_B = -100mA$
Collector-Enfitter Saturation Voltage (Note 9)	$V_{CE(sat)}$	-	-85	-130		$I_C = -2A$, $I_B = -200mA$
		-	-200	-260		$I_C = -5A$, $I_B = -500mA$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	-	-1	-1.15	V	$I_C = -5A$, $I_B = -500$ mV
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(on)}$	-	-0.89	-1.0	V	$I_{C} = -5A$, $V_{CE} = -2V$
Output Capacitance (Note 9)	C_obo	-	33	70	pF	V _{CB} = -10V. f = 1MHz
Transition Frequency	f _T	-	120	-	MHz	$V_{CE} = -10V, I_{C} = -100mA$ f = 50MHz
Outher Time	t _{on}	-	33	80		V _{CC} = -10V, I _C = -2A
Switching Time	t _{off}	-	215	300	ns	I _{B1} = -I _{B2} = -200mA

Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.





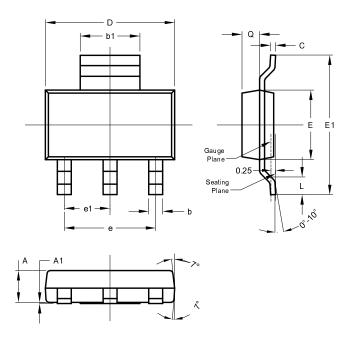
Typical Electrical Characteristics (@ $T_A = +25$ $^{\circ}$ C, unless otherwise specified.)





Package Outline Dimensions

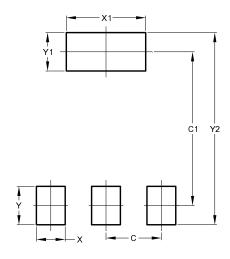
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A 1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00





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